

# High Voltage MOSFET

N-Channel, Enhancement Mode

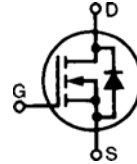
**IXTU 01N80**

**IXTY 01N80**

$V_{DSS} = 800 \text{ V}$

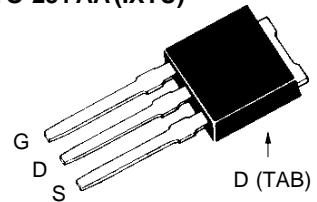
$I_{D25} = 100 \text{ mA}$

$R_{DS(on)} = 50 \text{ } \Omega$

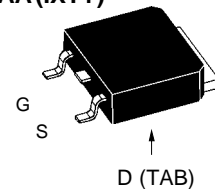


| Symbol        | Test Conditions  | Maximum Ratings<br>01N100 |                  |
|---------------|--|---------------------------|------------------|
| $V_{DSS}$     | $T_J = 25^\circ\text{C to } 150^\circ\text{C}$                             | 800                       | V                |
| $V_{DGR}$     | $T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GS} = 1 \text{ M}\Omega$ | 800                       | V                |
| $V_{GS}$      | Continuous   | $\pm 20$                  | V                |
| $V_{GSM}$     | Transient  | $\pm 30$                  | V                |
| $I_{D25}$     | $T_C = 25^\circ\text{C}; T_J = 25^\circ\text{C to } 150^\circ\text{C}$     | 100                       | mA               |
| $I_{DM}$      | $T_C = 25^\circ\text{C}$ , pulse width limited by max. $T_J$               | 400                       | mA               |
| $P_D$         | $T_C = 25^\circ\text{C}$   | 25                        | W                |
| $T_J$         |  | -55 ... +150              | $^\circ\text{C}$ |
| $T_{JM}$      |  | 150                       | $^\circ\text{C}$ |
| $T_{stg}$     |  | -55 ... +150              | $^\circ\text{C}$ |
| $T_L$         | 1.6 mm (0.063 in) from case for 5 s  | 300                       | $^\circ\text{C}$ |
| <b>Weight</b> |  | 0.8                       | g                |

TO-251 AA (IXTU)



TO-252 AA (IXTY)



G = Gate,      D = Drain,  
S = Source,    TAB = Drain

| Symbol       | Test Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                                       |
|--------------|--|---|------|---------------------------------------|
|              |  | min.  | typ. | max.                                  |
| $V_{DSS}$    | $V_{GS} = 0 \text{ V}, I_D = 25 \text{ } \mu\text{A}$  | 800   |      | V<br>V                                |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 25 \text{ } \mu\text{A}$   | 2   |      | 4.5 V                                 |
| $I_{GSS}$    | $V_{GS} = \pm 20 \text{ V}_{DC}, V_{DS} = 0$   |   |      | $\pm 50 \text{ nA}$                   |
| $I_{DSS}$    | $V_{DS} = 0.8 \cdot V_{DSS}$<br>$V_{GS} = 0 \text{ V}$   |   |      | 10 $\mu\text{A}$<br>200 $\mu\text{A}$ |
| $R_{DS(on)}$ | $V_{GS} = 10 \text{ V}, I_D = I_{D25}$<br>Pulse test, $t \leq 300 \text{ ms}$ , duty cycle $d \leq 2 \%$ |   |      | 50 $\Omega$                           |

## Features

- International standard packages  
JEDEC TO-251 AA, TO-252 AA
- Low  $R_{DS(on)}$  HDMOS™ process
- Rugged polysilicon gate cell structure
- Fast switching times

## Applications

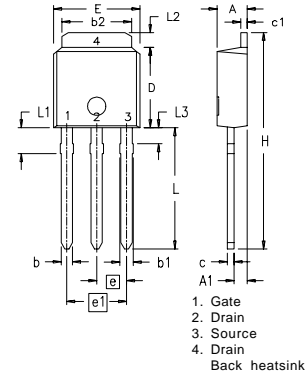
- Level shifting
- Triggers
- Solid state relays
- Current regulators

| Symbol       | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |      |
|--------------|---|---|------|------|
|              |   | min.  | typ. | max. |
| $g_{fs}$     | $V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$ , pulse test                                  |   | 140  | mS   |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$                                 |   | 60   | pF   |
| $C_{oss}$    |   |   | 8.0  | pF   |
| $C_{rss}$    |   |   | 2.0  | pF   |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 500\text{ V}, I_D = I_{D25}$<br>$R_G = 50\ \Omega$ (External) |   | 12   | ns   |
| $t_r$        |   |   | 12   | ns   |
| $t_{d(off)}$ |   |   | 28   | ns   |
| $t_f$        |   |   | 28   | ns   |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 I_{D25}$                         |   | 8    | nC   |
| $Q_{gs}$     |   |   | 1.8  | nC   |
| $Q_{gd}$     |   |   | 3    | nC   |
| $R_{thJC}$   |   |   | 3    | K/W  |

### Source-Drain Diode

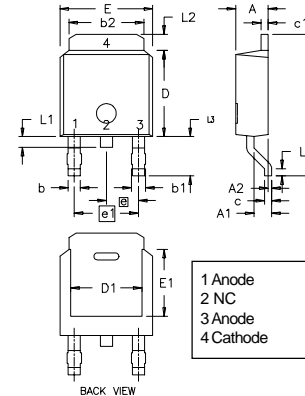
| Symbol   | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                   |
|----------|---|---|------|-------------------|
|          |   | min.  | typ. | max.              |
| $V_{SD}$ | $I_F = 100\text{ mA}, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |   |      | 1.5 V             |
| $t_{rr}$ | $I_F = 0.75\text{ A}, -di/dt = 10\text{ A}/\mu\text{s}$ ,<br>$V_{DS} = 25\text{ V}$                             |   |      | 1.5 $\mu\text{s}$ |

### TO-251 AA Outline



| Dim. | Millimeter |       | Inches |      |
|------|------------|-------|--------|------|
|      | Min.       | Max.  | Min.   | Max. |
| A    | 2.19       | 2.38  | .086   | .094 |
| A1   | 0.89       | 1.14  | 0.35   | .045 |
| b    | 0.64       | 0.89  | .025   | .035 |
| b1   | 0.76       | 1.14  | .030   | .045 |
| b2   | 5.21       | 5.46  | .205   | .215 |
| c    | 0.46       | 0.58  | .018   | .023 |
| c1   | 0.46       | 0.58  | .018   | .023 |
| D    | 5.97       | 6.22  | .235   | .245 |
| E    | 6.35       | 6.73  | .250   | .265 |
| e    | 2.28       | BSC   | .090   | BSC  |
| e1   | 4.57       | BSC   | .180   | BSC  |
| H    | 17.02      | 17.78 | .670   | .700 |
| L    | 8.89       | 9.65  | .350   | .380 |
| L1   | 1.91       | 2.28  | .075   | .090 |
| L2   | 0.89       | 1.27  | .035   | .050 |
| L3   | 1.15       | 1.52  | .045   | .060 |

### TO-252 AA



| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 2.19       | 2.38  | 0.086  | 0.094 |
| A1   | 0.89       | 1.14  | 0.035  | 0.045 |
| A2   | 0          | 0.13  | 0      | 0.005 |
| b    | 0.64       | 0.89  | 0.025  | 0.035 |
| b1   | 0.76       | 1.14  | 0.030  | 0.045 |
| b2   | 5.21       | 5.46  | 0.205  | 0.215 |
| c    | 0.46       | 0.58  | 0.018  | 0.023 |
| c1   | 0.46       | 0.58  | 0.018  | 0.023 |
| D    | 5.97       | 6.22  | 0.235  | 0.245 |
| D1   | 4.32       | 5.21  | 0.170  | 0.205 |
| E    | 6.35       | 6.73  | 0.250  | 0.265 |
| E1   | 4.32       | 5.21  | 0.170  | 0.205 |
| e    | 2.28       | BSC   | 0.090  | BSC   |
| e1   | 4.57       | BSC   | 0.180  | BSC   |
| H    | 9.40       | 10.42 | 0.370  | 0.410 |
| L    | 0.51       | 1.02  | 0.020  | 0.040 |
| L1   | 0.64       | 1.02  | 0.025  | 0.040 |
| L2   | 0.89       | 1.27  | 0.035  | 0.050 |
| L3   | 2.54       | 2.92  | 0.100  | 0.115 |

IXYS reserves the right to change limits, test conditions, and dimensions.



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.